### **Transmissive Sensor**

#### **FEATURES**

- · Phototransistor output
- · Four mounting configurations
- · Accurate position sensing
- 0.125 in.(3.18 mm) slot width
- Choice of detector aperture
- 24.0 in.(610 mm) min. 26 AWG UL 1429 wire
- · Choice of opaque or IR transmissive housings

#### DESCRIPTION

The HOA088X/089X series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. Phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. This series allows the user to choose from available options: (1) mounting tab configuration, (2) detector aperture size, (3) electro-optical characteristics, and (4) housing materials.

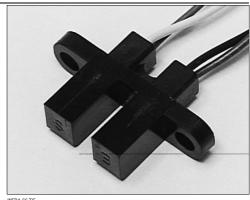
All devices employ a built-in strain relief for maximum wire attachment strength. The HOA088X series utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA089X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important and in situations where maximum position resolution is desired. The HOA088X/089X series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

The detector to emitter lead spacing is 0.32 in.(8.13 mm) for all versions. Wire color code and functions are:

Red - IRED Anode White - Detector Collector Black - IRED Cathode Green - Detector Emitter

To specify the complete product characteristics, see PART NUMBER GUIDE.



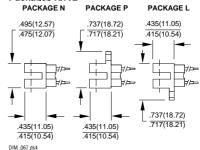
#### **OUTLINE DIMENSIONS** in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)

Package T 240(6,60) Æ 8e. .130(3.30 26 AWG CATED OPTICAL .130(3,30) .120(3,05) DIA 2 PLCS .355(9,01)

DIM 042 cdr

#### Packages N/P/L



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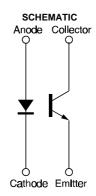
#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	IR			10	μΑ	V <sub>R</sub> =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V <sub>(BR)</sub> ceo	30			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current	Iceo			100	nA	V <sub>CE</sub> =10 V, I <sub>F</sub> =0
COUPLED CHARACTERISTICS On-State Collector Current Parameter A (HOA0880/0890) Parameter B (HOA0881/0891) Parameter C (HOA0882/0892)	Ic(on)	0.5 1.0 1.8			mA	V <sub>CE</sub> =10, I <sub>F</sub> =20 mA V <sub>CE</sub> =5 V, I <sub>F</sub> =10 mA V <sub>CE</sub> =0.6, I <sub>F</sub> =20 mA
Collector-Emitter Saturation Voltage Parameter A (HOA0880/0890) Parameter B (HOA0881/0891) Parameter C (HOA0882/0892)	VCE(SAT)			0.4 0.4 0.6	V	I <sub>C</sub> =0.4 mA, I <sub>F</sub> =20 mA I <sub>C</sub> =0.8 mA, I <sub>F</sub> =10 mA I <sub>C</sub> =1.8 mA, I <sub>F</sub> =20 mA
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>		15		μs	Vcc=5 V, Ic=1 mA $R_L$ =1000 $\Omega$

#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C -40°C to 85°C Storage Temperature Range Soldering Temperature (5 sec) 240°C IR EMITTER 100 mW (1) Power Dissipation Reverse Voltage 3 V Continuous Forward Current 50 mA DETECTOR 30 V Collector-Emitter Voltage **Emitter-Collector Voltage** 100 mW (1) Power Dissipation Collector DC Current 30 mA



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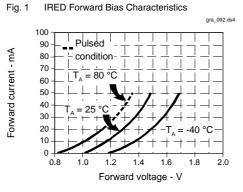
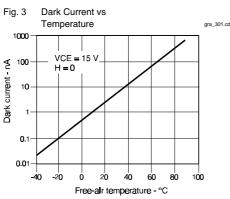
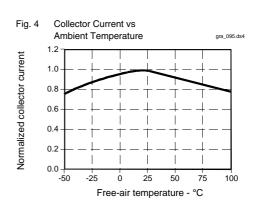


Fig. 2 Non-Saturated Switching Time vs Load Resistance gra\_093.ds4 Response time - us +1+1|++ 1.1.11111 TI IIII  $\exists \mp \Box \Box$ ПППП 1000 100 10 Load resistance - Ohms





All Performance Curves Show Typical Values

#### **PART NUMBER GUIDE**

with electrical Parameter A only

### HOA08XX-XXX

Housing Material

8 = Polysulfone, IR transmissive

9 = Polysulfone, opaque

Electrical Specifications

0 = Parameter A

1 = Parameter B

2 = Parameter C

\*0.010 in. (.25 mm) aperture available

\*1 = 0.010 in. (0.25 mm) 5 = 0.050 in. (1.27 mm) Aperture length is 0.060 in. (1.52 mm) **Aperture Width in Front Of IRED** 5 = 0.050 in. (1.27 mm) Aperture length is 0.060 in. (1.52 mm)

Aperture Width In Front Of Detector

Aperture length is 0.060 in. (1.52 mm)

Mounting Configuration
L = Single mounting tab, emitter side

N = No mounting tabs

P = Single mounting tab, detector side

T = Two mounting tabs

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